

Majorana zero modes in full-shell hybrid nanowires

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Introduction and motivation

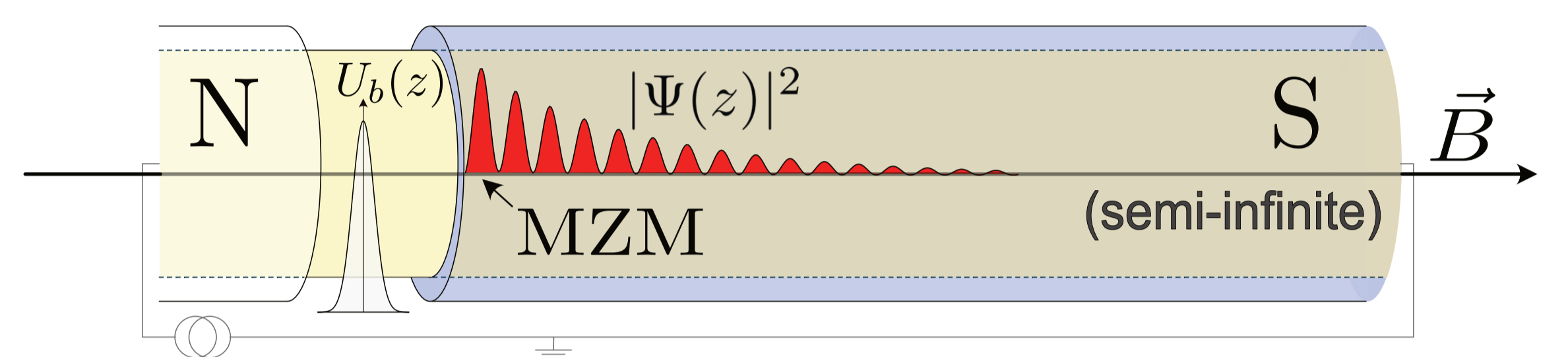
- **Full-shell hybrid nanowires** are a new platform in the search for **Majorana zero modes (MZMs)** with several advantages over previous devices.
- There are experimental claims of **MZMs** in this model¹.
- The system presents a **rich phenomenology**².
- **Our goal:** simulate the system's **edge LDOS** to understand the behavior of the **MZM** and other **in-gap states** with three levels of complexity:

- **Hollow-core:** 1D simplistic model, but **intuitive**.
- **Tubular-core:** 2D and charge **close to the interface**.
- **Solid-core:** full 2D simulation with a dome-like electrostatic potential radial profile.

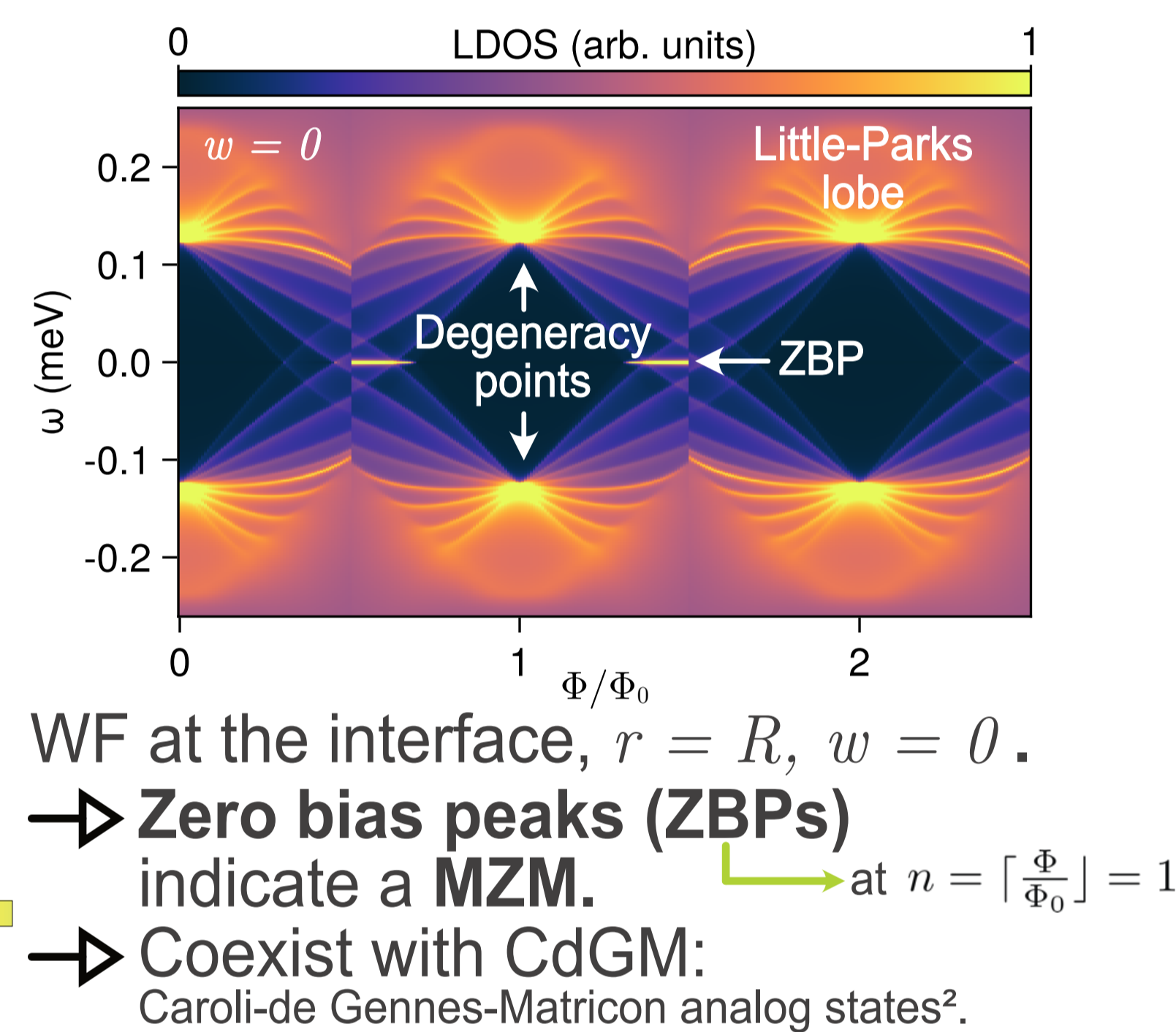
Device

- Ingredients
- **Semiconductor (SM)** nanowire with **strong spin-orbit coupling (SOC)**.
 - Encapsulated by a thin, **s-type superconductor shell (SC)**.
 - Threaded by a **magnetic flux**: $\Phi = \pi R^2 B$

We investigate MZMs: **zero-energy bound states** at the end of a **topological superconductor**.

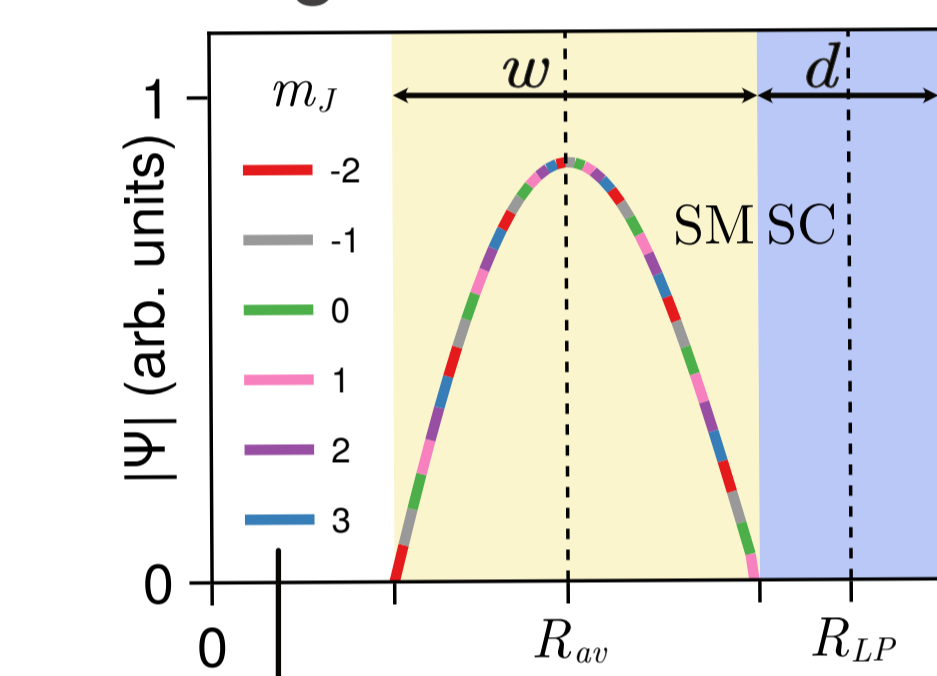


Hollow-core model

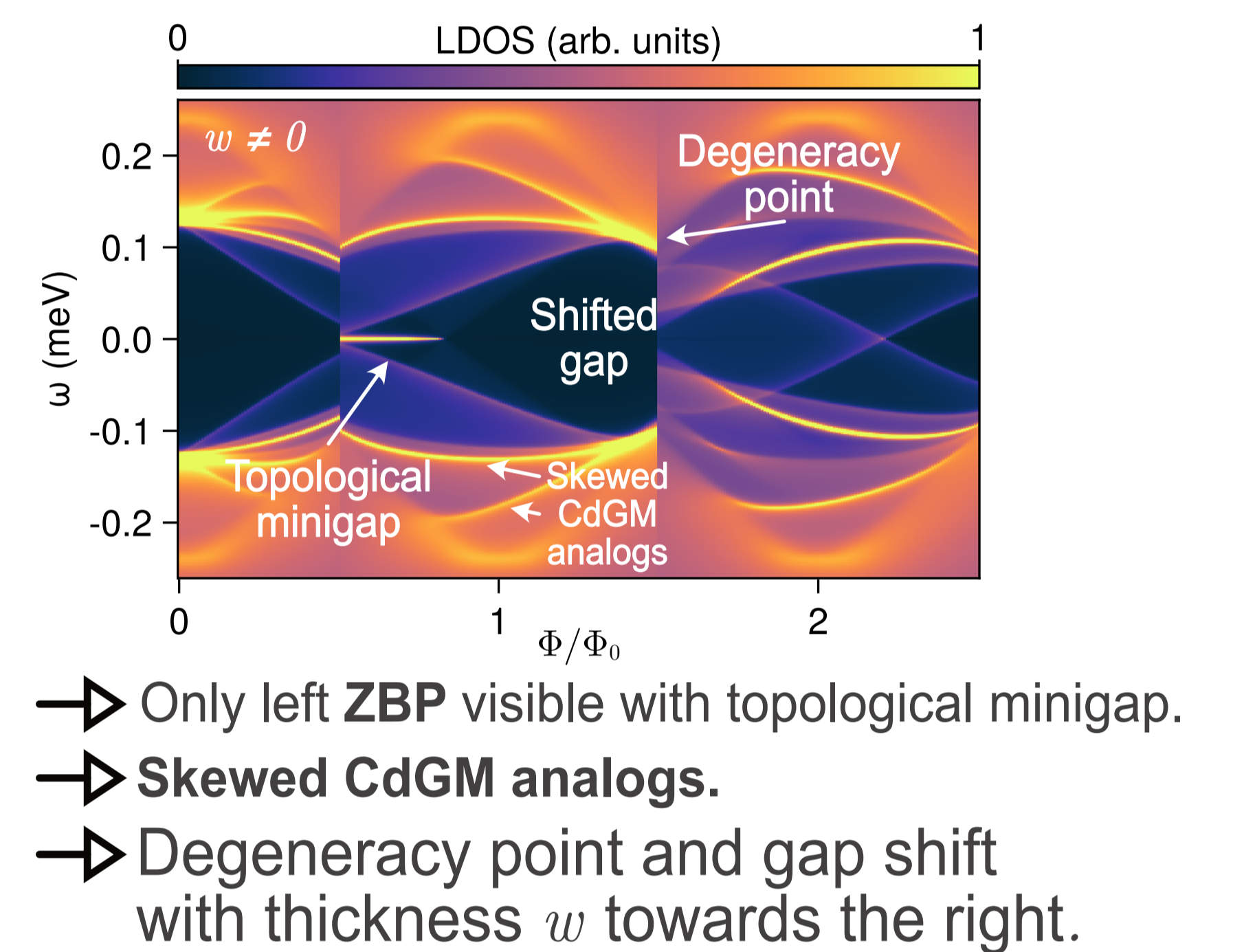


Tubular-core model

Wave-function (WF) confined to a region of thickness w .



LDOS at the edge of the nanowire.

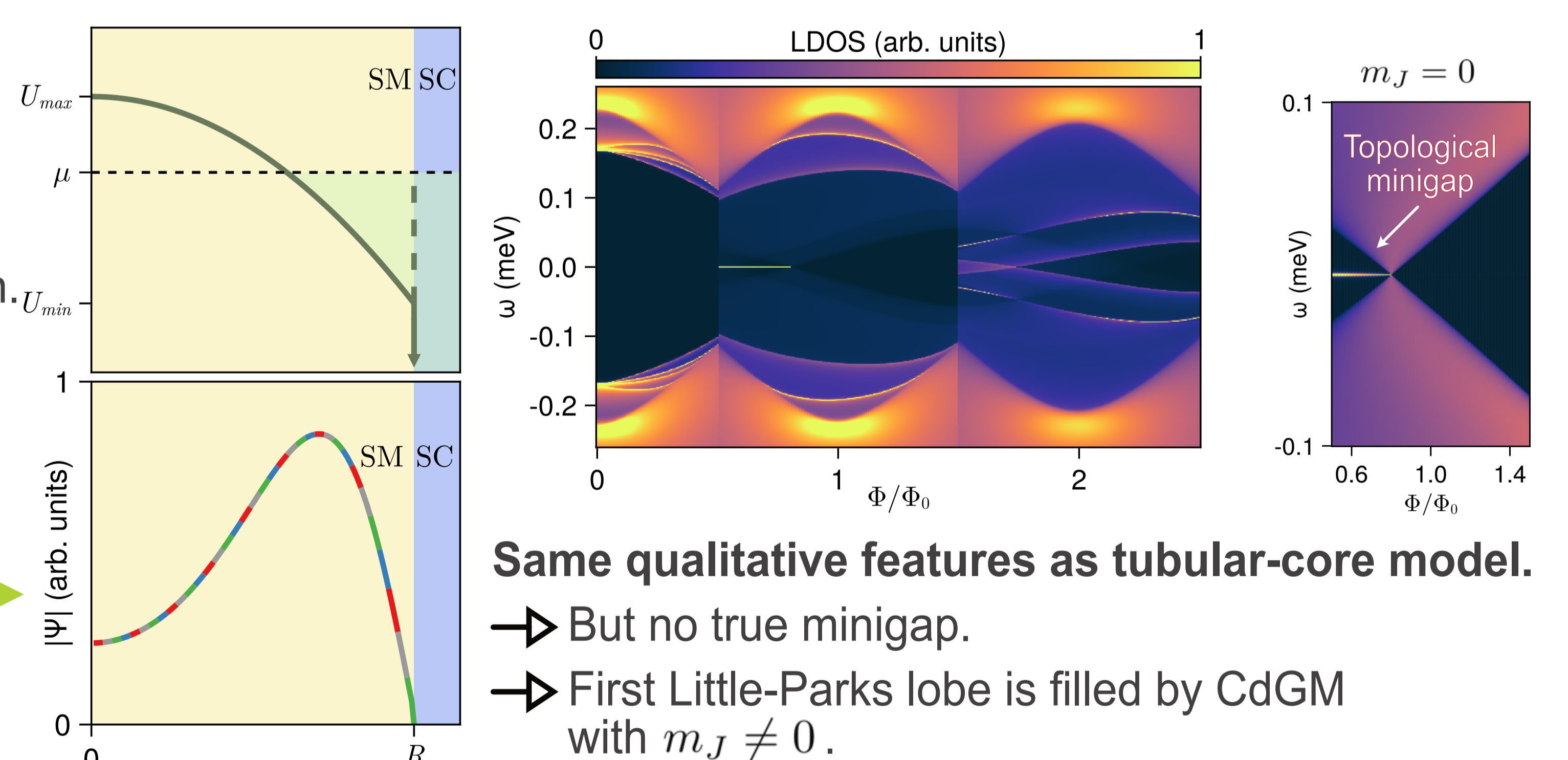
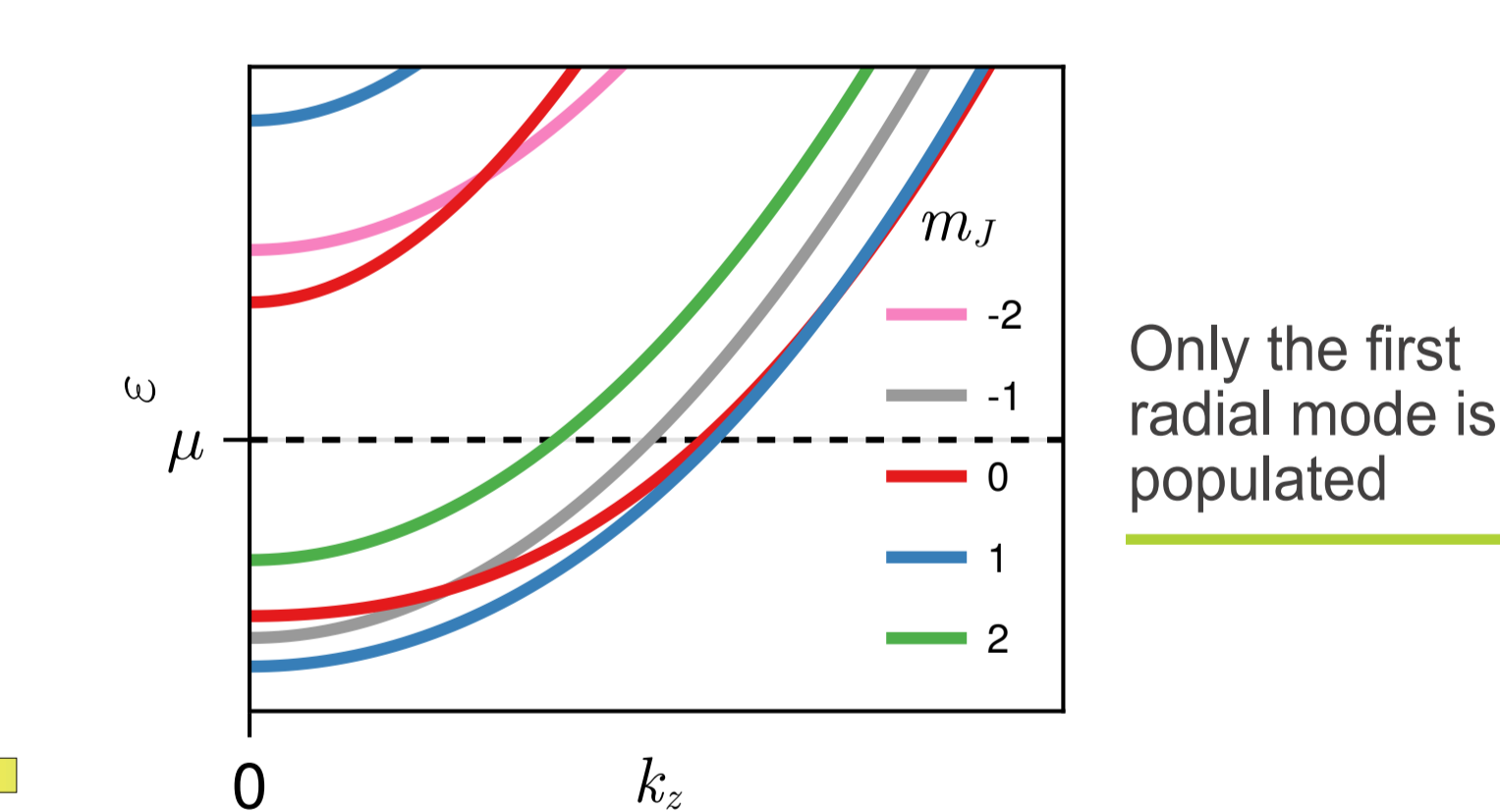


Solid Core model

$m_J = 0$ in first radial mode

Conduction band bends towards the interface.

WF spreads through all the SM section.



Conclusions

- MZM at hybrid nanowire's end \Rightarrow ZBP in LDOS odd Little-Parks lobes.
- In general, ZBP coexist with other sub-gap states called CdGM analogs.
- In the **tubular-core** nanowire, there can be true **topologically protected MZMs** (eg. minigap $\approx 40\mu\text{eV}$ for InAs/Al).
- In the **solid-core** nanowire, there is typically **no topological minigap** (only for fine-tuned parameters with negative SOC, the minigap is $\approx 30\mu\text{eV}$ for InAs/Al).

$m_J = 0$ in second radial mode

